

www.vishay.com

Vishay General Semiconductor

Dual Common Cathode Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance

TO-220AB





PRIMARY CHARACTERISTICS			
I _{F(AV)}	2 x 15 A		
V _{RRM}	60 V		
I _{FSM}	150 A		
V _F	0.59 V		
I _R	60 μΑ		
T _J max.	175 °C		
Package	TO-220AB		
Circuit configuration	Common cathode		

FEATURES

- Power pack
- Guardring for overvoltage protection
- · Lower power losses, high efficiency
- Low forward voltage drop
- Low leakage current
- · High forward surge capability
- High frequency operation
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, or polarity protection application.

MECHANICAL DATA

Case: TO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	MBR30H60CT	UNIT	
Maximum repetitive peak reverse voltage	V _{RRM}	60	V	
Working peak reverse voltage	V _{RWM}	60	V	
Maximum DC blocking voltage	V _{DC}	60	V	
total device		30	^	
Maximum average forward rectified current (fig. 1) per diode	I _{F(AV)}	15	A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	150	А	
Peak repetitive reverse surge current per diode at t_p = 2 μ s, 1 kHz	I _{RRM}	0.5	А	
Peak non-repetitive reverse energy (8/20 µs waveform)	E _{RSM}	20	mJ	
Non-repetitive avalanche energy per diode at 25 $^{\circ}$ C, I_{AS} = 4 A, L = 10 mH	E _{AS}	80	mJ	
Electrostatic discharge capacitor voltage human body model: $C=100~pF,~R=1.5~k\Omega$	V _C	25	kV	
Voltage rate of change (rated V _R)	dV/dt	10 000	V/µs	
Operating junction and storage temperature range	T _J , T _{STG}	-65 to +175	°C	



Vishay General Semiconductor

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	MBR30H60CT		UNIT
Maximum instantaneous forward voltage per diode	I _F = 15 A	T _C = 25 °C	V _F ⁽¹⁾	-	0.68	V
	I _F = 15 A	T _C = 125 °C		0.55	0.59	
	I _F = 30 A	T _C = 25 °C		-	0.83	
	I _F = 30 A	T _C = 125 °C		0.68	0.71	
Maximum reverse current per diode at working peak reverse voltage		T _J = 25 °C	I _R ⁽²⁾	-	60	μΑ
		T _J = 125 °C		4.0	15	mA

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	MBR	UNIT	
Typical thermal resistance junction to case per diode	$R_{ heta JC}$	1.5	°C/W	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AB	MBR30H60CT-E3/45	1.85	45	50/tube	Tube	

RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

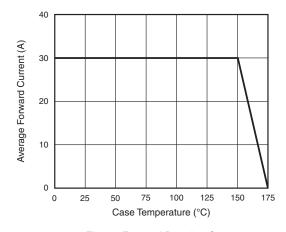


Fig. 1 - Forward Derating Curve

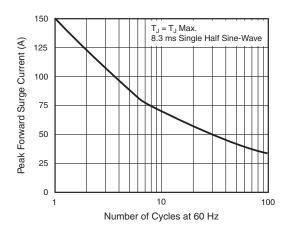


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode



Vishay General Semiconductor

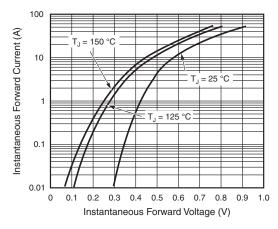


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

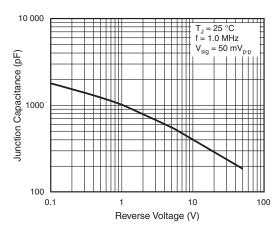


Fig. 5 - Typical Junction Capacitance Per Diode

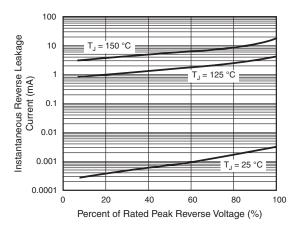


Fig. 4 - Typical Reverse Characteristics Per Diode

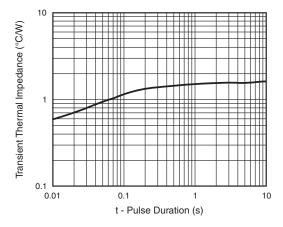
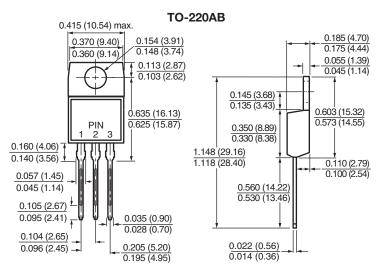


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Schottky Diodes & Rectifiers category:

Click to view products by Vishay manufacturer:

Other Similar products are found below:

CUS06(TE85L,Q,M) MA4E2039 D1FH3-5063 MBR0530L-TP MBR10100CT-BP MBR30H100MFST1G MMBD301M3T5G PMAD1103-LF PMAD1108-LF RB160M-50TR RB520S-30 RB551V-30 DD350N18K DZ435N40K DZ600N16K BAS16E6433HTMA1 BAS 3010S-02LRH E6327 BAT 54-02LRH E6327 IDL02G65C5XUMA1 NSR05F40QNXT5G JANS1N6640 SB07-03C-TB-H SB1003M3-TL-W SBAT54CWT1G SK32A-LTP SK33A-TP SK34A-TP SK34B-TP SMD1200PL-TP ACDBN160-HF SS3003CH-TL-E STPS30S45CW PDS3100Q-7 GA01SHT18 CRS10I30A(TE85L,QM MA4E2501L-1290 MBR1240MFST1G MBRB30H30CT-1G BAS28E6433HTMA1 BAS 70-02L E6327 HSB123JTR-E JANTX1N5712-1 VS-STPS40L45CW-N3 DD350N12K SB007-03C-TB-E SK110-LTP SK154-TP SK32A-TP SK33B-TP SK35A-TP